



The Future of Analog IC Technology®

MP4832

32-Channel High Voltage Analog Switch

PRELIMINARY SPECIFICATIONS SUBJECT TO CHANGE

DESCRIPTION

The MP4832 is a 32-channel high voltage single-pole single-throw, SPST, analog switch designed for medical ultrasound imaging applications. It is designed to multiplex the transmit and receive voltages to and from multiple piezoelectric transducers, PZTs.

The output switches are controlled by a 32-bit serial shift register followed by a 32-bit data latch. A data out, Dout, pin is provided to allow for multiple devices to be cascaded together. This will help minimize the number of input/output, I/O, control lines. A logic High in the data latch will turn on the corresponding analog switch whereas a logic Low will turn it off.

The MP4832 does not require any high voltage supplies. Only two low voltage supplies are required, 3.3V and 10V. The analog switch can block or pass analog voltages up to ±100V with peak currents of up to ±2.0A. The MP4832 is available in a QFN 72-pin 10mm x 10mm package.

FEATURES

- No High Voltage Supplies Required
- 32 Channels
- Up to ±100V Analog Signals
- 14 Ohms Typical Switch Resistance
- ±2.0A Typical Switch Peak Current
- Off-Isolation of -60dB at 5.0MHz
- 80MHz Clock Frequency

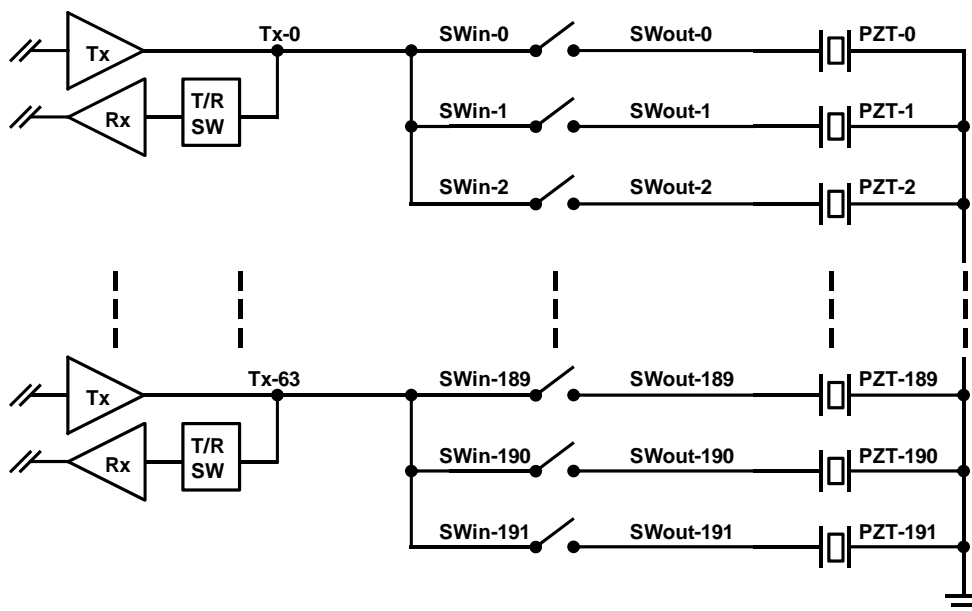
APPLICATIONS

- Medical Ultrasound Imaging
- NDT, Non-Destructive Testing

All MPS parts are lead-free, halogen free, and adhere to the RoHS directive. For MPS green status, please visit MPS website under Quality Assurance. "MPS" and "The Future of Analog IC Technology" are Registered Trademarks of Monolithic Power Systems, Inc.

Please email "ultrasoundproducts@monolithicpower.com" for more information

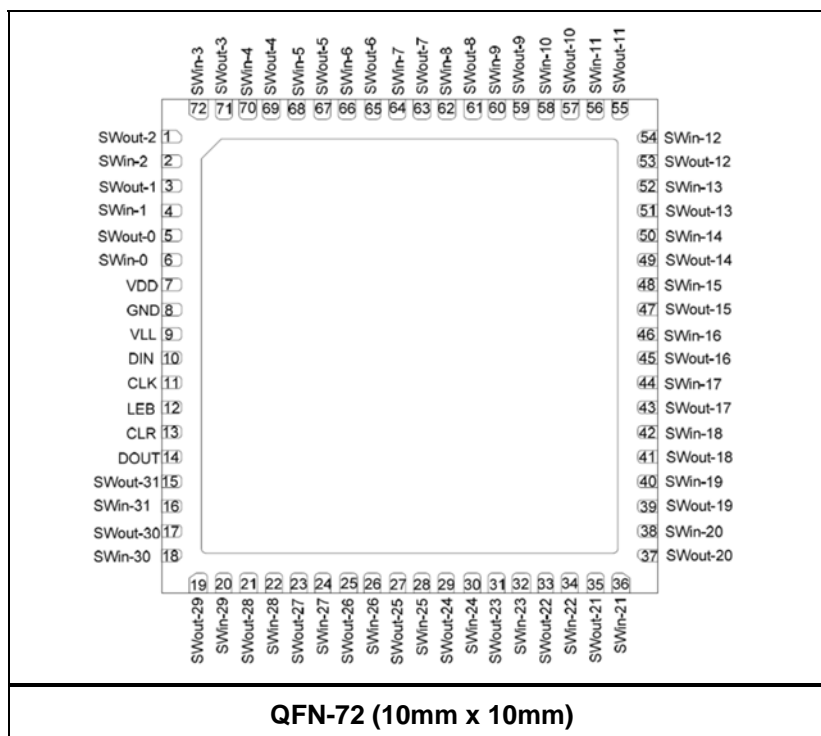
TYPICAL APPLICATION



ORDERING INFORMATION

Part Number*	Package	Top Marking
MP4832GRD	QFN-72 (10mm x 10mm)	TBD

* For Tape & Reel, add suffix -Z (e.g. MP4832GRD-Z).

PACKAGE REFERENCE

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

V_{LL} , Logic supply	-0.5V to +6.6V
V_{DD} , Translator supply.....	-0.5V to +11V
V_{SIG} , Analog signal range.....	0V to ± 120 V
Junction Temperature	150°C
Lead Temperature	260°C
Continuous Power Dissipation, $T_A=25^\circ\text{C}$ ⁽²⁾ .	TBD
Storage temperature	-55°C to 150°C

Recommended Operating Conditions ⁽³⁾

Logic supply voltage, V_{LL}	2.7V to 5.5V
Translator supply voltage, V_{DD}	9V to 10V
Analog signal range, V_{SIG}	0 to ± 100 V
Junction temperature, T_J	-25°C to +125°C

Thermal Resistance ⁽⁴⁾

	θ_{JA}	θ_{JC}
QFN-72 (10mm x 10mm)	15	3 °C/W

Notes:

- Exceeding these ratings may damage the device.
- The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = $(T_J$ (MAX) - T_A) / θ_{JA} . Exceeding the maximum allowable power dissipation will cause excessive die temperature resulting in permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- Measured on JESD51-7, 4-layer PCB.